

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S54	181	(gan or gallium near2 nitride) near10 (grading or graded)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 12:41
S53	9	single near2 crystal\$5 near5 (gan or gallium near2 nitride) near10 grad\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 12:41
S55	116	(gan or gallium near2 nitride) near10 (grading or graded) and (si or silicon) near5 (substrate or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 12:42
S56	17	(gan or gallium near2 nitride) near10 (grading or graded) near10 (crystal\$6 or monocrystal\$6) and (si or silicon) near5 (substrate or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 12:45
S57	211	(graded or grading) near14 (single near2 crystal\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 13:59
S59	7	(gan or gallium near2 nitride) near10 composit\$6 near5 var\$4 near16 single	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 14:00
S58	62	(gan or gallium near2 nitride) near10 composit\$6 near5 var\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/16 14:00
S61	7	(grading or graded) near15 (gan or gallium near2 nitride or algan) near15 (single near2 crystal or monocrystal\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/19 10:37
S60	217	(grading or graded) near15 (gan or gallium near2 nitride or algan)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/19 10:37

EAST Search History

S41	2	(hugues near2 marchand or brendan near2 moran).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 15:14
L4	2	(hugues near2 marchand or brendan near2 moran).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 15:14